

FQU2N100TU

FQU2N100TU Information





Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



FQU2N100TU Specifications

Manufacturer Part Number	FQU2N100TU	
Manufacturer	Fairchild/ON Semiconductor	
Category	Discrete Semiconductor Products	
	Transistors - FETs, MOSFETs - Single	
Package	TO-251-3 Short Leads, IPak, TO-251AA	
Series	QFET?	
FET Type	N-Channel	
Technology	MOSFET (Metal Oxide)	
Drain to Source Voltage (Vdss)	1000V	
Current - Continuous Drain (Id) @ 25°C	1.6A (Tc)	
Drive Voltage (Max Rds On, Min Rds On)	10V	
Vgs(th) (Max) @ Id	5V @ 250µA	
Gate Charge (Qg) (Max) @ Vgs	15.5nC @ 10V	
Input Capacitance (Ciss) (Max) @ Vds	520pF @ 25V	
Vgs (Max)	±30V	
FET Feature	-	
Power Dissipation (Max)	2.5W (Ta), 50W (Tc)	
Rds On (Max) @ Id, Vgs	9 Ohm @ 800mA, 10V	
Operating Temperature	-55°C ~ 150°C (TJ)	
Mounting Type	Through Hole	
Supplier Device Package	I-Pak	
Package / Case	TO-251-3 Short Leads, IPak, TO-251AA	
		Report errors?

FQU2N100TU Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

FQU2N100TU Payment Methods



FQU2N100TU Shipping Methods



If you have any question about FQU2N100TU, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com